

1 Probing the Effect of Metal to Ligand Charge Transfer on the Oxygen 2 Evolution Reaction in Au Incorporated Co(OH)₂ Thin Film Electrocatalysts

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11 Supporting Information

12 13 14 Sample preparation and electrochemical experiments:

15 Three solutions were prepared in three separate 25 ml volumetric flasks. 10 mM Co(NO₃)₂ was prepared from Co(NO₃)₂·6H₂O.
16 0.0726g of the salt was taken in a 25 ml volumetric flask and dissolved in water. In another 25 ml volumetric flask 0.0726g
17 of Co(NO₃)₂·6H₂O and 0.0139g of KAuBr₄·H₂O were taken and dissolved in water to prepare a Au incorporated Co(NO₃)₂
18 solution where the concentration of Au was 10% of Co concentration. 1mM Au solution was prepared from dissolving
19 0.0139g of KAuBr₄·H₂O in a third 25 ml volumetric flask. Co(OH)₂, Co(OH)₂-Au were electrodeposited on three types of
20 substrates according to the following table:

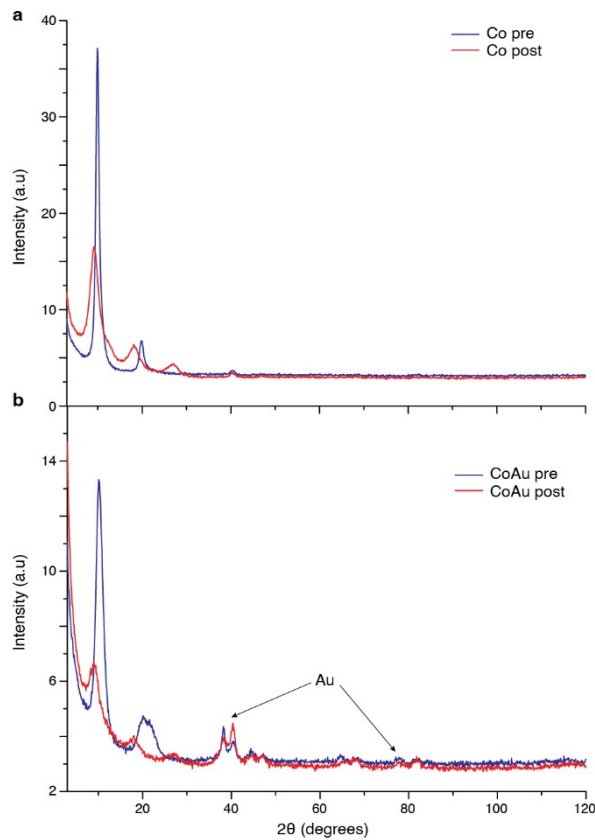
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22 Table S1: Sample preparation

Sample	Substrate	Deposition time	Experiment name
Co(OH) ₂	Glassy carbon stick electrode	60s	All electrochemical experiments
	Pt coated Silicon wafer	60s	XPS, TEM
Co(OH) ₂ -Au	Pt coated Silicon wafer	300s	SEM, EDX, XRD
	Pt coated Si ₃ N ₄ windows	60s	NEXAFS

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24 Au film was deposited on glassy carbon stick electrode and Pt coated Silicon wafer only, to perform cyclic voltammetry and
25 XPS (Figure 1 and 4).

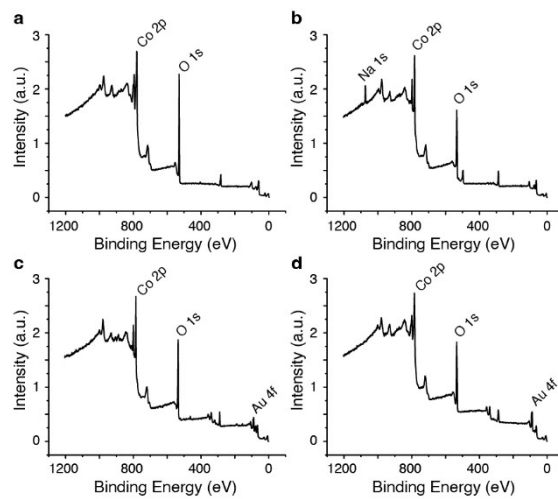
26 The Si wafer and the Si₃N₄ windows were first coated with a 2nm Ti adhesive layer followed by a 10nm Pt layer by electron
27 beam to increase their conductivity. The films were electrodeposited from the prepared solutions using a potentiostat in a
28 typical three electrode system where a Ag/AgCl electrode was used as the reference electrode and Pt wire was used as
29 counter. Applied voltage for the electrodeposition was -1.05V vs Ag/AgCl. After deposition the films were subjected to OER
30 at 0.75V vs Ag/AgCl for 4 hrs in 0.1M NaOH solution. Au films were not subjected to the 4 hr OER. Cyclic voltammograms
31 (CV) for Co(OH)₂, Co(OH)₂-Au and Au films were recorded between a range of 0.9 – 1.66 V (vs RHE) at a sweep rate of 20
32 mVs⁻¹ in 0.1 M NaOH to measure their electrochemical performance. To measure electrochemical surface area (ECSA) CV
33 was performed on Co(OH)₂ and Co(OH)₂-Au films at various scan rates in the double layer charging region of both films.

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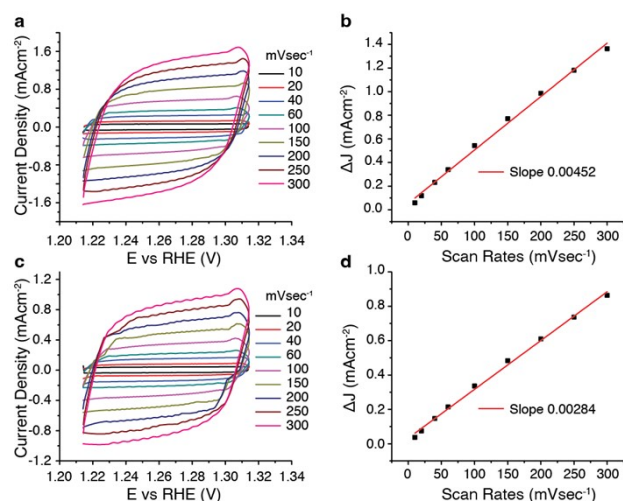
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Figure S1: XRD images of (a) Co(OH)₂ and (b) Co(OH)₂-Au films before and after the OER show presence of crystalline Au *hkl*-111 and *hkl*-311 planes at 2θ of 38° and 77°.¹



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43 Figure S2: XPS survey scans of (a) Co(OH)₂ pre, (b) Co(OH)₂ post, (c) Co(OH)₂-Au pre and (d) Co(OH)₂-Au post OER films show
44 presence of Co 2p, O 1s in all four films, Na 1s in Co post and Au 4f in Co(OH)₂-Au films.



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47 Figure S3. (a) and (c) Cyclic voltammograms recorded for Co(OH)₂ and Co(OH)₂-Au films in 0.1M NaOH at various scan rates
 48 in the double layer charging region. (b) and (d) Plots of capacitive current obtained at 1.26 V vs RHE against sweep rate.

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50 The surface area was determined from the slope of the plots in Figure S3 (b) and (d) which is given below in Table S2. The
 51 electrochemically active surface area was calculated by assuming that a flat surface has a specific capacitance of 40 μFcm⁻²
 52 for Co(OH)₂.²

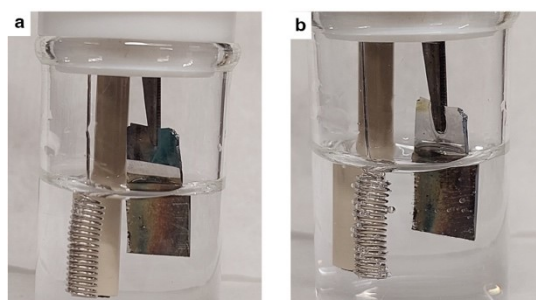
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54 Table S2. Electrochemically active surface area of Co and CoAu thin films.

Sample	Slope	ECSA (cm ²)
Co(OH) ₂	0.00452	113
Co(OH) ₂ -Au	0.00284	71

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58 Figure S4: (a) Electrodeposited Co(OH)₂-Au film on Si wafer submerged in 0.1M NaOH before applying voltage, (b) Oxygen
 59 bubbles accumulating on the Co(OH)₂-Au film surface after applying the voltage for OER.

60 References

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2. H. Deng, C. Zhang, Y. Xie, T. Tumlin, L. Giri, S. P. Karna and J. Lin, *Journal of Materials Chemistry A*, 2016, **4**, 6824-6830.

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